HIGH-SPE	ED 2.5V <i>IDT70T3509M</i>
1024K x 3	6
1024K x 3 SYNCHRO DUAL-POR	NOUS
DUAL-POI	RT STATIC RAM
	OR 2.5V INTERFACE
	SS - LAST TIME BUY EXPIRES JUNE 15, 2018
Features:	– Data input, address, byte enable and control registers
True Dual-Port memory cells which allow simultaneous	 Self-timed write allows fast cycle time
access of the same memory location	 Separate byte controls for multiplexed bus and bus matching compatibility
 High-speed data access Commercial: 4.2ns (133MHz)(max.) 	 Dual Cycle Deselect (DCD) for Pipelined Output Mode
– Industrial: 4.2ns (133MHz)(max.)	 2.5V (±100mV) power supply for core
 Selectable Pipelined or Flow-Through output mode 	 LVTTL compatible, selectable 3.3V (±150mV) or 2.5V
 Counter enable and repeat features Interrupt Flags 	(±100mV) power supply for I/Os and control signals on each port
 Full synchronous operation on both ports 	 Includes JTAG functionality
- 7.5ns cycle time, 133MHz operation (9.5Gbps bandwidth)	Available in a 256-pin Ball Grid Array (BGA)
- 1.5ns setup to clock and 0.5ns hold on all control, data, and	Common BGA footprint provides design flexibility over
address inputs @ 133MHz – Fast 4.2ns clock to data out	 seven density generations (512K to 36M-bit) Green parts available, see ordering information
	Green parts available, see or doring information
Functional Block Diagram	
FT/PIPEL 100 1a 0b 1b 0c 1c 0d 1d	
Dout0-8.L Dout0-7.L Dout1-7.L	Dout0-8,R Dout9-7,R Dout9-7,R
	Oa ta Ob Ib. Oc to Od ta
AQL COUNTER/	ADDR_R Counter/ Address REPEATR
ADS Reg.	N Reg. ADSR CNTENR

NOTES:

1. The sleep mode pin shuts off all dynamic inputs, except JTAG inputs, when asserted. All static inputs, i.e., PL/FTx and OPTx and the sleep mode pins themselves (ZZx) are not affected during sleep mode.

ZZL⁽¹⁾

ZZ CONTROL LOGIC ZZR⁽¹⁾

2. See Truth Table I for Functionality.

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Description:

The IDT70T3509M is a high-speed 1024K x 36 bit synchronous Dual-Port RAM. The memory array utilizes Dual-Port memory cells to allow simultaneous access of any address from both ports. Registers on control, data, and address inputs provide minimal setup and hold times. The timing latitude provided by this approach allows systems to be designed with very short cycle times. With an input data register, the IDT70T3509M has been optimized for applications having unidirectional or bidirectional data flow in bursts. An automatic power down feature, controlled by \overline{CE}_0 and CE1, permits the on-chip circuitry of each port to enter a very low standby power mode.

The 70T3509M can support an operating voltage of either 3.3V or 2.5V on one or both ports, controllable by the OPT pins. The power supply for the core of the device (VDD) is at 2.5V.

Pin Configuration (1,2,3,4)

08/03/04

70T3509M BP BP-256^(5,7)

256-Pin BGA Top View⁽⁶⁾

						-								
^{A2}	A3	A4	A5	A6	A7	A8	A9	A10	A11	A12	A13	A14	A15	A16
TDI	A19L	A17L	A14L	A11L	A8L	BE2L	CE1L	OEL	CNTENL	A5L	A2L	Aol	NC	NC
^{B2}	^{B3}	B4	B5	B6	B7	B8	B9	^{B10}	B11	B12	B13	^{B14}	в15	^{B16} NC
NC	TDO	A18L	A15L	A12L	A9L	BE3L	CEOL	R∕₩L	REPEATL	A4L	A1L	Vdd	I/O17L	
C2	C3	C4	C5	C6	C7	C8	C9	C10	C11	C12	С13	C14	C15	C16
I/O19L	Vss	A16L	A13L	A10L	A7∟	BE1L	BE0L	CLKL	ADSL	A6L	АзL	OPT∟	I/O17R	I/O16L
D2	d3	d4	d5	d6	d7	d8	d9	d10	d11	d12	d13	D14	D15	D16
I/O19R	I/O20L	PIPE/FTL	Vddql	Vddql	Vddqr	Vddqr	Vddql	Vddql	Vddqr	Vddqr	Vdd	I/O15R	I/O15L	I/O16R
e2	e3	e4	e5	e6	e7	^{E8}	^{E9}	E10	e11	e12	e13	е14	e15	e16
I/O21l	I/O22L	Vddql	Vdd	Vdd	INTl	Vss	Vss	Vss	Vdd	Vdd	Vddqr	I/O13L	I/O14L	I/O14r
f2	f3	f4	f5	F6	F7	^{F8}	^{F9}	F10	F11	f12	f13	F14	F15	F16
I/O22R	I/O23r	Vddql	Vdd	NC	NC	Vss	Vss	Vss	Vss	Vdd	Vddqr	I/O12R	I/O13R	I/O12L
G2	G3	g4	G5	G6	G7	G8	^{G9}	G10	G11	G12	g13	G14	g15	G16
I/O24L	I/O25L	Vddqr	Vss	Vss	Vss	Vss	Vss	Vss	Vss	Vss	Vddql	I/O10L	I/O11L	I/O11R
h2	h3	h4	H5	H6	^{H7}	H8	H9	H10	H11	H12	h13	h14	^{H15}	h16
I/O25r	I/O26R	Vddqr	Vss	Vss	Vss	Vss	Vss	Vss	Vss	Vss	Vddql	I/O9r	IO9∟	I/O10r
j2	j3	j4	J5	^{J6}	J7	_{J8}	^{J9}	J10	J11	J12	j13	J14	j15	J16
I/O28R	I/O27R	Vddql	ZZr	Vss	Vss	Vss	Vss	Vss	Vss	ZZL	Vddqr	I/O8R	I/O7r	I∕O8∟
k2	k3	k4	к5	к ₆	кт	ка	к9	K10	K11	к12	k13	k14	к15	к16
I/O29L	I/O28l	Vddql	Vss	Vss	Vss	Vss	Vss	Vss	Vss	Vss	Vddqr	I/O6r	I/O6l	I/O7L
l2	l3	l4	ls	L6	L7	L8	L9	L10	L11	l12	l13	l14	l15	l16
I/O31R	I/O30r	Vddqr	Vdd	NC	NC	Vss	Vss	Vss	Vss	Vdd	Vddql	I/O5l	I/O4r	I/O5r
m2	m3	m4	^{M5}	M6	m7	M8	^{M9}	M10	M11	m12	m13	m14	^{M15}	™16
I/O32l	I/O31l	Vddqr	Vdd	Vdd	ĪNTr	Vss	Vss	Vss	Vdd	Vdd	Vddql	I/O3r	I∕O3∟	I/O4L
N2 I/O34R	n3 I/O33r	N4 PIPE/FTr	n5 Vddqr	n6 Vddqr	n7 Vddql	n8 Vddql	n9 Vddqr	n10 Vddqr			n13 Vdd	n14 I/O2l	n15 I/O1r	n16 I/O2r
p2	^{P3}	P4	P5	P6	P7	P8	P9	P10	^{p11}	P12	Р13	P14	p15	Р16
I/O34L	TMS	A16R	A13R	A10R	A7R	BE1R	BE0R	CLKR	ADSr	A6R	Азк	I/Ool	I/Oor	I/O1L
R2	^{R3}	R4	R5	R6	r7	r8	^{R9}	^{R10}	r11	R12	r13	^{R14}	^{R15}	R16
NC	TRST	A18R	A15R	A12R	A9r	BE3r	CEor	R/Wr	REPEATR	A4R	A1r	OPTr	NC	NC
T2	t3	t4	t5	t6	t7	t8	^{T9}	T10	t11	t12	t13	T14	T15	^{т16}
TCK	A19R	A17R	A14r	A11r	A8r	BE2r	CE1r	OEr	CNTENR	A5r	A2r	Aor	NC	NC
	TDI ^{B2} NC ^{C2} I/O19L ^{D2} I/O19R ^{E2} I/O21L ^{F2} I/O24L ^{H2} I/O24L ^{H2} I/O28R ^{K2} I/O28R ^{K2} I/O29L ^{L2} I/O31R ^{M2} I/O34R ^{P2} I/O34L ^{R2}	TDI A19L B2 B3 TDO C2 C3 TDO D2 D3 J/O19R D/O20L E2 D3 J/O21L B3 J/O19R D/O20L B3 J/O20L E2 J/O19R D/O20L B3 J/O21L E3 J/O20L B3 J/O22R F3 J/O25R J/O25R J/O25R J/O26R J/O26R J/O27R J/O25R J/O27R J/O27R J/O27R J/O25R J/O27R J/O27R J/O27R K2 J/O28L L3 J/O37R J/O29L L3 J/O37R J/O37R J/O31R J/O307R J/O31L J/O31L N2 J/O34R N3 J/O33R P2 J/O34L TMS TMS R2 R3 TMS TMS	TDI A19L A17L B2 B3 A17L B2 C3 C4 I/O19L VSS C4 D2 D3 D4 I/O19L VSS PIPE/FTL E2 E3 I/O20L PIPE/FTL E2 F3 I/O20L PIPE/FTL I/O21L I/O20L F4 VDDQL F2 F3 I/O25L VDDQL G2 G3 I/O25L VDDQL I/O24L I/O25L VDDQL VDQL J2 J3 I/O27R VDDQL I/O28R I/O27R VDDQL VDQL K2 I/O28R I/O27R VDQL I/O28R I/O27R VDQQL VDQQL K2 I/O28R I/O27R VDQQL K2 I/O31R VDQQR VDQQR M2 I/O31R I/O30R PIPE/FTR I/O34R I/O33R PIPE/FTR P2	TDI A19L A17L A14L B2 B3 B4 B5 A15L C2 C3 C4 C5 A13L D2 D3 D4 PIPL A13L D5 D2 D3 D4 PIPL/FTL D5 VDDQL E2 F3 V/O22R VDDQL F5 VDDQ F2 I/O22R F3 VDDQL F5 VDD F2 I/O22R F3 VDDQR F5 VDD F2 I/O22R I/O25R VDDQR F5 VDD G2 J3 J4 VDDQR VSS J2 I/O28R I/O27R VDDQR VSS VSS J2 J3 J4 J5 VSS J/O28R I/O28R VDDQR VSS VSS L2 L3 L4 L5 VDD VDD J/O31R I/O31R VDDQR VDDQR VDD VDD	TDI A19L A17L A14L A11L B2 B3 B4 B5 B6 A12L C2 C3 C4 C5 G6 A10L D2 D3 D4 D5 G6 A10L D2 D3 D4 D5 G6 A10L D2 D3 D4 D5 D6 VDDQL E2 I/O20L F4 D5 D6 VDDQL F2 I/O22R F4 VDDQL F5 D6 VDDQ F2 I/O22R F4 VDDQR F4 D5 F6 I/O22R I/O25R F4 VDDQR F5 D6 VDD F2 I/O25R I/O25R F4 VDDQR F5 F6 VD I/O25R I/O25R VDDQR VDDQR VSS F4 S5 F6 I/O25R I/O27R VDDQR VDDQR VSS F4 S5 <td< td=""><td>TDI A19L A17L A14L A11L A8L B2 B3 TDO A18L B5 A12L A9L C2 C3 C4 C5 C6 C7 A7L D2 D3 D4 D5 D0 D7DO D7DO D2 D3 D4 D5 D6 D7 I/O19R D3 D4 D5 D0 D7DO I/O19R D3 D4 D5 D0 D7DO I/O19R D3 D4 D5 D0 D7DO I/O21L F3 PIPE/FTL D5DOL D6 D7 I/O22R F3 VDDQL F5 D5 F6 T7 I/O24L G3 D4 D5 PS S5 T0 T5 I/O25R I/O26R P4 D5 M5 T5 T5 T5 I/O24L G3 L4 D5 M5 T5</td><td>TDI A19L A17L A14L A11L A8L BE2L B2 B3 DO B4 B5 L12L B7AL B8 B5 L12L B7AL B8 B5 L12L B7AL B8 B5 L12L C7 C8 B1L C7 C8 C8</td><td>TDI A19L A17L A14L A11L A8L BE2L CE1L B2 C3 B4 B5 B6 A12L B7 B8 B5 B6 C2 I/O19I VSS C4 C5 A13L C6 A7 C8 BE1L C9 D2 D3 D4 D5 D6 D1 VD0R VSS VSS</td><td>TDI A19L A17L A14L A11L A8L BE2L CE1L OEL B2 B3 TDO A18L B5 B6 A12L B7 B8 B7 B7 B7 B7 B7 B7 B7 C10 C1</td><td>TDI A19L A17L A14L A11L A8L BE2L CE1L OEL CNTENL B2 B3 D A18L B15 B6 B7 B8 B9 B10 R/WL BE11 C2 VSS C4 C5 A13L C6 C7 C8 C9 C10 C11 AD5L D2 D3 D4 D5 C6 D7 D8 D9 D10 D10 D11 VD201 I/O202 PIPE/FTL D5 D6 D7 D8 D9 D10 D10 VDDQ VDD VSS VSS<td>TDI A19L A17L A14L A11L A8L BE2L CE1L OEL TONL A5L B2 B3 B4 A18L A15L A12L A9L B8 B9 B10 R/WL REPATL A4L C2 C3 VSS A16L A13L A10L A7L C8 BE1L BE0L C10L C11 D12 VAGU VDOQL VDOQ VDQ</td></td></td<> <td>TDI A19L A17L A14L A11L A8L BE2L CE1L OEL OTTENL ASL ASL B2 B3 TDO A18L B5 B6 B1 B7 B8 B2 B2 B10 RFPEATL B11 B12 B13 A4 B11 B12 B13 B12 B13<!--</td--><td>TDI A19. A17. A14. A11. A8. BE2. CE1. OE. CNTEN. AS. A2. A0. B2 B3 TDO A18. B5 A12. B7. B8 B8. B9 B10. R/W. REPEAL B14. B13. B14. VDD C2 C3 C4 A16. C5 A13. C6 C7. C8 C10. C11. D12. C13. C14. OPT. D2 D3 D4 D5 D5 D6 D7. D8 D9 D10. D12. D12. D13. D14. U/O15. E2 B1//O2. P1PE/FT. D5 D6 D7 D8 D9 D10. D11. D12. D13. D14. U/O15. E2 B3 P4 D5 D6 D7 D7 D8 D5 D10. D14. U/D15. D14. U/D15. D14. U/D15. D14.<td>TDI A19L A14L A11L A8L BE2 CE1L OTEL OTEL A5L A2L A0L NC B2 B3 TDO A18L B5 B5 A15L B1 B1 B1 B13 B14 B13 M1L B14 B15 J017L C2 VSS A16L C5 C6 C7 C8 C9 C10 C11 A3L C14 C15 J017L J012</td></td></td>	TDI A19L A17L A14L A11L A8L B2 B3 TDO A18L B5 A12L A9L C2 C3 C4 C5 C6 C7 A7L D2 D3 D4 D5 D0 D7DO D7DO D2 D3 D4 D5 D6 D7 I/O19R D3 D4 D5 D0 D7DO I/O19R D3 D4 D5 D0 D7DO I/O19R D3 D4 D5 D0 D7DO I/O21L F3 PIPE/FTL D5DOL D6 D7 I/O22R F3 VDDQL F5 D5 F6 T7 I/O24L G3 D4 D5 PS S5 T0 T5 I/O25R I/O26R P4 D5 M5 T5 T5 T5 I/O24L G3 L4 D5 M5 T5	TDI A19L A17L A14L A11L A8L BE2L B2 B3 DO B4 B5 L12L B7AL B8 B5 L12L B7AL B8 B5 L12L B7AL B8 B5 L12L C7 C8 B1L C7 C8 C8	TDI A19L A17L A14L A11L A8L BE2L CE1L B2 C3 B4 B5 B6 A12L B7 B8 B5 B6 C2 I/O19I VSS C4 C5 A13L C6 A7 C8 BE1L C9 D2 D3 D4 D5 D6 D1 VD0R VSS VSS	TDI A19L A17L A14L A11L A8L BE2L CE1L OEL B2 B3 TDO A18L B5 B6 A12L B7 B8 B7 B7 B7 B7 B7 B7 B7 C10 C1	TDI A19L A17L A14L A11L A8L BE2L CE1L OEL CNTENL B2 B3 D A18L B15 B6 B7 B8 B9 B10 R/WL BE11 C2 VSS C4 C5 A13L C6 C7 C8 C9 C10 C11 AD5L D2 D3 D4 D5 C6 D7 D8 D9 D10 D10 D11 VD201 I/O202 PIPE/FTL D5 D6 D7 D8 D9 D10 D10 VDDQ VDD VSS VSS <td>TDI A19L A17L A14L A11L A8L BE2L CE1L OEL TONL A5L B2 B3 B4 A18L A15L A12L A9L B8 B9 B10 R/WL REPATL A4L C2 C3 VSS A16L A13L A10L A7L C8 BE1L BE0L C10L C11 D12 VAGU VDOQL VDOQ VDQ</td>	TDI A19L A17L A14L A11L A8L BE2L CE1L OEL TONL A5L B2 B3 B4 A18L A15L A12L A9L B8 B9 B10 R/WL REPATL A4L C2 C3 VSS A16L A13L A10L A7L C8 BE1L BE0L C10L C11 D12 VAGU VDOQL VDOQ VDQ	TDI A19L A17L A14L A11L A8L BE2L CE1L OEL OTTENL ASL ASL B2 B3 TDO A18L B5 B6 B1 B7 B8 B2 B2 B10 RFPEATL B11 B12 B13 A4 B11 B12 B13 B12 B13 </td <td>TDI A19. A17. A14. A11. A8. BE2. CE1. OE. CNTEN. AS. A2. A0. B2 B3 TDO A18. B5 A12. B7. B8 B8. B9 B10. R/W. REPEAL B14. B13. B14. VDD C2 C3 C4 A16. C5 A13. C6 C7. C8 C10. C11. D12. C13. C14. OPT. D2 D3 D4 D5 D5 D6 D7. D8 D9 D10. D12. D12. D13. D14. U/O15. E2 B1//O2. P1PE/FT. D5 D6 D7 D8 D9 D10. D11. D12. D13. D14. U/O15. E2 B3 P4 D5 D6 D7 D7 D8 D5 D10. D14. U/D15. D14. U/D15. D14. U/D15. D14.<td>TDI A19L A14L A11L A8L BE2 CE1L OTEL OTEL A5L A2L A0L NC B2 B3 TDO A18L B5 B5 A15L B1 B1 B1 B13 B14 B13 M1L B14 B15 J017L C2 VSS A16L C5 C6 C7 C8 C9 C10 C11 A3L C14 C15 J017L J012</td></td>	TDI A19. A17. A14. A11. A8. BE2. CE1. OE. CNTEN. AS. A2. A0. B2 B3 TDO A18. B5 A12. B7. B8 B8. B9 B10. R/W. REPEAL B14. B13. B14. VDD C2 C3 C4 A16. C5 A13. C6 C7. C8 C10. C11. D12. C13. C14. OPT. D2 D3 D4 D5 D5 D6 D7. D8 D9 D10. D12. D12. D13. D14. U/O15. E2 B1//O2. P1PE/FT. D5 D6 D7 D8 D9 D10. D11. D12. D13. D14. U/O15. E2 B3 P4 D5 D6 D7 D7 D8 D5 D10. D14. U/D15. D14. U/D15. D14. U/D15. D14. <td>TDI A19L A14L A11L A8L BE2 CE1L OTEL OTEL A5L A2L A0L NC B2 B3 TDO A18L B5 B5 A15L B1 B1 B1 B13 B14 B13 M1L B14 B15 J017L C2 VSS A16L C5 C6 C7 C8 C9 C10 C11 A3L C14 C15 J017L J012</td>	TDI A19L A14L A11L A8L BE2 CE1L OTEL OTEL A5L A2L A0L NC B2 B3 TDO A18L B5 B5 A15L B1 B1 B1 B13 B14 B13 M1L B14 B15 J017L C2 VSS A16L C5 C6 C7 C8 C9 C10 C11 A3L C14 C15 J017L J012

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NOTES:

1. All VDD pins must be connected to 2.5V power supply.

- 2. All VDDO pins must be connected to appropriate power supply: 3.3V if OPT pin for that port is set to VDD (2.5V), and 2.5V if OPT pin for that port is set to Vss (0V).
- 3. All Vss pins must be connected to ground supply.
- 4. Package body is approximately 17mm x 17mm x 1.76mm, with 1.0mm ball-pitch.
- 5. This package code is used to reference the package diagram.
- 6. This text does not indicate orientation of the actual part-marking.
- 7. BP-256 package thickness is 1.76mm nominal. This is thicker than the BC-256 package (1.40mm nominal) used for the lower density IDT dual-port products.

IDT70T3509M

High-Speed 2.5V 1024K x 36 Dual-Port Synchronous Static RAM

Pin Names

Left Port	Right Port	Names					
CE0L, CE1L	CEOR, CE1R	Chip Enables (Input) ⁽⁵⁾					
R/WL	R/Wr	Read/Write Enable (Input)					
ŌĒL	ŌĒr	Output Enable (Input)					
Aol - A19l	Aor - A19r	Address (Input)					
VOOL - VO35L	1/O0r - 1/O35r	Data Input/Output					
CLKL	CLKR	Clock (Input)					
PL/ FT L	PL/FTr	Pipeline/Flow-Through (Input)					
ADSL	ADSR	Address Strobe Enable (Input)					
	CNTENR	Counter Enable (Input)					
REPEATL REPEATR		Counter Repeat ⁽³⁾ (Input)					
BEOL - BE3L	BEOR - BE3R	Byte Enables (9-bit bytes) (Input) ⁽⁵⁾					
VDDQL	VDDQR	Power (I/O Bus) (3.3V or 2.5V) ⁽¹⁾ (Input)					
OPTL	OPTR	Option for selecting VDDox ^(1,2) (Input)					
ZZL	ZZR	Sleep Mode pin ⁽⁴⁾ (Input)					
V	DD	Power (2.5V) ⁽¹⁾ (Input)					
V	SS	Ground (OV) (Input)					
٦	DI	Test Data Input					
Т	DO	Test Data Output					
Т	СК	Test Logic Clock (10MHz) (Input)					
Т	MS	Test Mode Select (Input)					
TF	RST	Reset (Initialize TAP Controller) (Input)					
ĪNTL	ĪNTr	Interrupt Flag (Output)					

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NOTES:

- 1. VDD, OPTx, and VDDox must be set to appropriate operating levels prior to applying inputs on the I/Os and controls for that port.
- 2. OPTx selects the operating voltage levels for the I/Os and controls on that port. If OPTx is set to VDD (2.5V), then that port's I/Os and controls will operate at 3.3V levels and VDDOX must be supplied at 3.3V. If OPTx is set to Vss (0V), then that port's I/Os and address controls will operate at 2.5V levels and VDDOX must be supplied at 2.5V. The OPT pins are independent of one another-both ports can operate at 3.3V levels, both can operate at 2.5V levels, or either can operate at 3.3V with the other at 2.5V.

3. When $\overline{\text{REPEAT}} x$ is asserted, the counter will reset to the last valid address loaded via ADSx.

4. The sleep mode pin shuts off all dynamic inputs, except JTAG inputs, when asserted. All static inputs, i.e., PL/FTx and OPTx and the sleep mode pins themselves (ZZx) are not affected during sleep mode. It is recommended that boundary scan not be operated during sleep mode.

5. Chip Enables and Byte Enables are double buffered when PL/FT = VIH, i.e., the signals take two cycles to deselect.

Hig	h-Spee	d 2.5\	/ 102	4K x 🗄	36 Dua	al-Port	Syncl	nronou	s Stat	ic RAM			Com	mercial Temperature Range
Tru	th T	abl	e I–	-Re	ad/\	Nrit	e ar	nd E	nab	le Co	ntrol	(1,2,3,4)		
ŌĒ	CLK		CE1	BE 3	BE ₂	BE1	BE 0	R/W	zz	Byte 3 I/O27-35	Byte 2 I/O18-26	Byte 1 I/O9-17	Byte 0 I/O ₀₋₈	MODE
Х	\uparrow	Н	L	Х	Х	Х	Х	Х	L	High-Z	High-Z	High-Z	High-Z	Deselected-Power Down
Х	\uparrow	L	L	Х	Х	Х	Х	Х	Х	Active	Active	Active	Active	Not Allowed
Х	\uparrow	Н	Н	Х	Х	Х	Х	Х	Х	Active	Active	Active	Active	Not Allowed
Х	\uparrow	L	Н	Н	Н	Н	Н	Х	L	High-Z	High-Z	High-Z	High-Z	All Bytes Deselected
Х	\uparrow	L	Н	н	Н	Н	L	L	L	High-Z	High-Z	High-Z	Din	Write to Byte 0 Only
Х	\uparrow	L	Н	н	Н	L	Н	L	L	High-Z	High-Z	Din	High-Z	Write to Byte 1 Only
Х	\uparrow	L	Н	н	L	Н	Н	L	L	High-Z	Din	High-Z	High-Z	Write to Byte 2 Only
Х	\uparrow	L	Н	L	Н	Н	Н	L	L	Din	High-Z	High-Z	High-Z	Write to Byte 3 Only
Х	\uparrow	L	Н	н	Н	L	L	L	L	High-Z	High-Z	Din	Din	Write to Lower 2 Bytes Only
Х	\uparrow	L	Н	L	L	Н	Н	L	L	Din	Din	High-Z	High-Z	Write to Upper 2 bytes Only
Х	\uparrow	L	Н	L	L	L	L	L	L	Din	Din	Din	Din	Write to All Bytes
L	\uparrow	L	Н	н	Н	Н	L	Н	L	High-Z	High-Z	High-Z	Dout	Read Byte 0 Only
L	\uparrow	L	Н	н	Н	L	Н	Н	L	High-Z	High-Z	Dout	High-Z	Read Byte 1 Only
L	\uparrow	L	Н	н	L	Н	Н	Н	L	High-Z	Dout	High-Z	High-Z	Read Byte 2 Only
L	\uparrow	L	Н	L	Н	Н	Н	Н	L	Dout	High-Z	High-Z	High-Z	Read Byte 3 Only
L	\uparrow	L	Н	Н	Н	L	L	Н	L	High-Z	High-Z	Dout	Dout	Read Lower 2 Bytes Only
L	\uparrow	L	Н	L	L	Н	Н	Н	L	Dout	Dout	High-Z	High-Z	Read Upper 2 Bytes Only
L	\uparrow	L	Н	L	L	L	L	Н	L	Dout	Dout	Dout	Dout	Read All Bytes
Н	\uparrow	Х	Х	Х	Х	Х	Х	Х	L	High-Z	High-Z	High-Z	High-Z	Outputs Disabled
Х	Х	Х	Х	Х	Х	Х	Х	Х	Н	High-Z	High-Z	High-Z	High-Z	Sleep Mode

NOTES:

1. "H" = VIH, "L" = VIL, "X" = Don't Care.

2. $\overline{\text{ADS}}$, $\overline{\text{CNTEN}}$, $\overline{\text{REPEAT}}$ = X.

IDT70T3509M

3. $\overline{\text{OE}}$ and ZZ are asynchronous input signals.

4. It is possible to read or write any combination of bytes during a given access. A few representative samples have been illustrated here.

Truth Table II—Address Counter Control^(1,2)

Address	Previous Internal Address	Internal Address Used	CLK	ADS	CNTEN	REPEAT ⁽⁶⁾	I/O ⁽³⁾	MODE
An	Х	An	Ŷ	L ⁽⁴⁾	Х	Н	Dvo (n)	External Address Used
Х	An	An + 1	Ŷ	Н	L ⁽⁵⁾	Н	D⊮o(n+1)	Counter Enabled—Internal Address generation ⁽⁷⁾
Х	An + 1	An + 1	Ŷ	Н	Н	Н	D⊮o(n+1)	External Address Blocked—Counter disabled (An + 1 reused)
Х	Х	An	Ŷ	Х	Х	L ⁽⁴⁾	Di/o(n)	Counter Set to last valid ADS load
								5682 tbl 03

5682 tbl 02

NOTES:

1. "H" = VIH, "L" = VIL, "X" = Don't Care.

2. Read and write operations are controlled by the appropriate setting of R/W, CE0, CE1, BEn and OE.

3. Outputs configured in flow-through output mode: if outputs are in pipelined mode the data out will be delayed by one cycle.

4. ADS and REPEAT are independent of all other memory control signals including CE0, CE1 and BEn

5. The address counter advances if CNTEN = VIL on the rising edge of CLK, regardless of all other memory control signals including CEo, CE1, BEn.

6. When REPEAT is asserted, the counter will reset to the last valid address loaded via ADS. This value is not set at power-up: a known location should be loaded via ADS during initialization if desired. Any subsequent ADS access during operations will update the REPEAT address location.

7. Address A19 must be managed as part of a full depth counter implementation using the IDT70T3509M. For physical addresses 00000H through 7FFFH the value of a A19 is 0, while for physical addresses 80000H through FFFFH the value of A19 is 1. The user needs to keep track of the device counter and make sure that A19 is actively driven from 0-to-1 or 1-to-0 and held as needed at the appropriate address boundaries for full depth counter operation and that A19 is in the appropriate state when using the REPEAT function.

Recommended Operating Temperature and Supply Voltage ⁽¹⁾

Grade	Ambient Temperature	GND	Vdd
Commercial	$0^{\circ}C$ to $+70^{\circ}C$	0V	2.5V <u>+</u> 100mV
Industrial	-40°C to +85°C	0V	2.5V <u>+</u> 100mV
			5692 tbl 04

NOTES:

1. This is the parameter TA. This is the "instant on" case temperature.

Recommended DC Operating Conditions with VDD0 at 2.5V

Symbol	Parameter	Min.	Тур.	Max.	Unit
Vdd	Core Supply Voltage	2.4	2.5	2.6	V
VDDQ	I/O Supply Voltage ⁽³⁾	2.4	2.5	2.6	V
Vss	Ground	0	0	0	V
Vін	Input High Volltage (Address, Control & Data I/O Inputs) ⁽³⁾	1.7		Vddq + 100mV ⁽²⁾	v
Vih	Input High Voltage - JTAG	1.7		Vdd + 100mV ⁽²⁾	V
Vih	Input High Voltage - ZZ, OPT, PIPE/FT	Vdd - 0.2V		Vdd + 100mV ⁽²⁾	V
VIL	Input Low Voltage	-0.3(1)		0.7	V
Vı∟	Input Low Voltage - ZZ, OPT, PIPE/FT	-0.3(1)		0.2	v

NOTES:

5682 tbl 05a

5682 tbl 05b

1. VIL (min.) = -1.0V for pulse width less than tcyc/2 or 5ns, whichever is less.

2. VIH (max.) = VDDQ + 1.0V for pulse width less than tcyc/2 or 5ns, whichever is less.

3. To select operation at 2.5V levels on the I/Os and controls of a given port, the OPT pin for that port must be set to $V_{SS}(0V)$, and V_{DDOX} for that port must be supplied as indicated above.

Recommended DC Operating Conditions with VDDO at 3.3V

Conditions with VDDQ at 3.3V							
Symbol	Parameter	Min.	Тур.	Max.	Unit		
Vdd	Core Supply Voltage	2.4	2.5	2.6	V		
Vddq	I/O Supply Voltage ⁽³⁾	3.15	3.3	3.45	V		
Vss	Ground	0	0	0	V		
Vih	Input High Voltage (Address, Control &Data I/O Inputs) ⁽³⁾	2.0		Vddq + 150mV ⁽²⁾	V		
Vih	Input High Voltage - JTAG	1.7		VDD + 100mV ⁽²⁾	V		
Vін	Input High Voltage - ZZ, OPT, PIPE/FT	Vdd - 0.2V		VDD + 100mV ⁽²⁾	V		
VIL	Input Low Voltage	-0.3(1)		0.8	V		
VIL	Input Low Voltage - ZZ, OPT, PIPE/FT	-0.3(1)		0.2	V		

NOTES:

1. VIL (min.) = -1.0V for pulse width less than tcyc/2, or 5ns, whichever is less.

2. VIH (max.) = VDDQ + 1.0V for pulse width less than tcyc/2 or 5ns, whichever is less.

 To select operation at 3.3V levels on the I/Os and controls of a given port, the OPT pin for that port must be set to VDD (2.5V), and VDDOX for that port must be supplied as indicated above.

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Com'l & Ind	Unit
Vterm (Vdd)	Vod Terminal Voltage with Respect to GND	-0.5 to 3.6	V
Vterm ⁽²⁾ (Vddq)	VDDQ Terminal Voltage with Respect to GND	-0.3 to VDDQ + 0.3	V
V _{TERM⁽²⁾ (INPUTS and I/O's)}	Input and I/O Terminal Voltage with Respect to GND	-0.3 to VDDQ + 0.3	V
TBIAS ⁽³⁾	Temperature Under Bias	-55 to +125	°C
Tstg	Storage Temperature	-65 to +150	°C
ицТ	Junction Temperature	+150	٥C
IOUT(For VDDQ = 3.3V)	DC Output Current	50	mA
IOUT(For VDDQ = 2.5V)	DC Output Current	40	mA
NOTES			5682 tbl 06

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. This is a steady-state DC parameter that applies after the power supply has reached its nominal operating value. Power sequencing is not necessary; however, the voltage on any Input or I/O pin cannot exceed VDDo during power supply ramp up.
- 3. Ambient Temperature under DC Bias. No AC Conditions. Chip Deselected.

Capacitance⁽¹⁾

(TA = +	25°C,	F =	1.0MHz) BGA ONLY
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Symbo	I Parameter	Conditions	Max.	Unit
Cin	Input Capacitance	VIN = 0V	35	рF
Cout ⁽²	Output Capacitance	Vout = 0V	35	pF
				5682 tbl 07

NOTES:

 These parameters are determined by device characterization, but are not production tested.

2. COUT also references CI/o.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range (VDD = 2.5V ± 100mV)

			70T35	09MS	
Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Lu	Input Leakage Current ⁽¹⁾	VDDQ = Max., V IN = 0 V to V DDQ		20	μA
Lu	JTAG & ZZ Input Leakage Current ^(1,2)	VDD = Max., VIN = 0V to VDD		60	μA
Ilo	Output Leakage Current ^(1,3)	$\overline{CE}_0 = V_{IH} \text{ and } CE_1 = V_{IL}, V_{OUT} = 0V \text{ to } V_{DDQ}$		20	μA
Vol (3.3V)	Output Low Voltage ⁽¹⁾	IOL = +4mA, $VDDQ = Min$.		0.4	V
Voн (3.3V)	Output High Voltage ⁽¹⁾	IOH = -4mA, VDDQ = Min.	2.4		V
Vol (2.5V)	Output Low Voltage ⁽¹⁾	IOL = +2mA, $VDDQ = Min$.		0.4	V
Voн (2.5V)	Output High Voltage ⁽¹⁾	Ioh = -2mA, VDDQ = Min.	2.0		V

NOTES:

1. VDDQ is selectable (3.3V/2.5V) via OPT pins. Refer to p.5 for details.

2. Applicable only for TMS, TDI and TRST inputs.

3. Outputs tested in tri-state mode.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range (3) (VDD = 2.5V ± 100mV)

•		70T3509MS13: Com'l & Ind				m'l	
Symbol	Parameter	Test Condition	Versio	Version		Мах.	Uni
IDD	Dynamic Operating		COM'L	S	800	1120	
	Current (Both Ports Active)	Outputs Disabled, f = fMAX ⁽¹⁾	IND	S	800	1370	mA
ISB1 ⁽⁶⁾	Standby Current	$\overline{CEL} = \overline{CER} = VIH$	COM'L	S	560	760	m ^
	(Both Ports - TTL Level Inputs)	$f = fMAX^{(1)}$		S	560	940	mA
ISB2 ⁽⁶⁾	Standby Current (One Port - TTL	$\overline{CE}^{"}A^{"} = VIL and \overline{CE}^{"}B^{"} = VIH^{(5)}$	COM'L	S	680	880	
	Level Inputs)	Active Port Outputs Disabled, f=fMAX ⁽¹⁾	IND	S	680	1090	mA
ISB3	Full Standby Current	Both Ports $\overline{CE}_{OL} = \overline{CE}_{OR} \ge V_{DDQ} - 0.2V$ and	COM'L	S	20	60	
	(Both Ports - CMOS Level Inputs)	$\begin{array}{l} \mbox{CE1L} = \mbox{CE1R} \leq 0.2V, \\ \mbox{VIN} \geq \mbox{VDDQ} \ \ - \ \ 0.2V \ \ \ or \ \ \ VIN \leq 0.2V, \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	IND	S	20	80	mA
ISB4 ⁽⁶⁾	Full Standby Current (One Port - CMOS		COM'L	S	680	880	m ^
	Level Inputs)	$VIN \ge VDDQ - 0.2V$ or $VIN \le 0.2V$ Active Port, Outputs Disabled, f = fMAX ⁽¹⁾		S	680	1090	mA
lzz	Sleep Mode Current	ZZL = ZZR = VIH	COM'L	S	20	60	
	(Both Ports - TTL Level Inputs)	f=fMAX ⁽¹⁾	IND	S	20	80	mA
						56	82 tbl

NOTES:

1. At f = fmax, address and control lines (except Output Enable) are cycling at the maximum frequency clock cycle of 1/tcyc, using "AC TEST CONDITIONS".

2. f = 0 means no address, clock, or control lines change. Applies only to input at CMOS level standby.

- 3. Port "A" may be either left or right port. Port "B" is the opposite from port "A".
- 4. VDD = 2.5V, TA = 25°C for Typ, and are not production tested. IDD DC(f=0) = 30mA (Typ).
- 5. $\overline{CE}x = VIL$ means $\overline{CE}ox = VIL$ and CE1x = VIH (enabled)
 - $\overline{CE}x = VIH$ means $\overline{CE}ox = VIH$ and CE1x = VIL (disabled)

 $\overline{CE}x \le 0.2V$ means \overline{CE} ox $\le 0.2V$ and $CE_{1X} \ge V_{DDQ} - 0.2V$ (enabled - CMOS levels)

 $\overline{CEx} \ge VDDQ - 0.2V$ means \overline{CE} $x \ge VDDQ - 0.2V$ and $CE_{1x} \le 0.2V$ (disabled - CMOS levels)

"X" represents "L" for left port or "R" for right port.

6. ISB1, ISB2 and ISB4 will all reach full standby levels (ISB3) on the appropriate port(s) if ZZL and/or ZZR = VIH.

IDT70T3509M High-Speed 2.5V 1024K x 36 Dual-Port Synchronous Static RAM

AC Test Conditions (VDDQ - 3.3V/2.5V)

Input Pulse Levels (Address & Controls)	GND to 3.0V/GND to 2.4V		
Input Pulse Levels (I/Os)	GND to 3.0V/GND to 2.4V		
Input Rise/Fall Times	2ns		
Input Timing Reference Levels	1.5V/1.25V		
Output Reference Levels	1.5V/1.25V		
Output Load	Figure 1		

5682 tbl 10

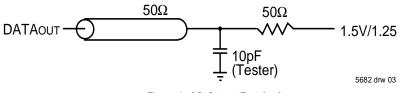
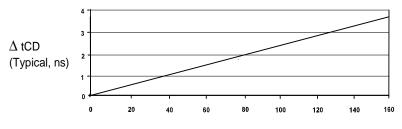


Figure 1. AC Output Test load.



 Δ Capacitance (pF) from AC Test Load 5682 drw 04

High-Speed 2.5V 1024K x 36 Dual-Port Synchronous Static RAM

AC Electrical Characteristics Over the Operating Temperature Range (Read and Write Cycle Timing) $^{(2,3)}$ (VDD = 2.5V ± 100mV, TA = 0°C to +70°C)

		70T3509 Con & Ir	70T3509MS133 Com'l & Ind		
Symbol	Parameter	Min.	Мах.	Unit	
tcyc1	Clock Cycle Time (Flow-Through) ⁽¹⁾	25		ns	
tcyc2	Clock Cycle Time (Pipelined) ⁽¹⁾	7.5		ns	
tсн1	Clock High Time (Flow-Through) ⁽¹⁾	10		ns	
tCL1	Clock Low Time (Flow-Through) ⁽¹⁾	10		ns	
tCH2	Clock High Time (Pipelined) ⁽²⁾	3		ns	
tCL2	Clock Low Time (Pipelined) ⁽¹⁾	3		ns	
tsa	Address Setup Time	1.8		ns	
tha	Address Hold Time	0.5		ns	
tsc	Chip Enable Setup Time	1.8		ns	
tнc	Chip Enable Hold Time	0.5		ns	
tsв	Byte Enable Setup Time	1.8		ns	
tнв	Byte Enable Hold Time	0.5		ns	
tsw	R/W Setup Time	1.8		ns	
tHW	R/W Hold Time	0.5		ns	
tsp	Input Data Setup Time	1.8		ns	
thd	Input Data Hold Time	0.5		ns	
tsad	ADS Setup Time	1.8		ns	
thad	ADS Hold Time	0.5		ns	
tscn	CNTEN Setup Time	1.8		ns	
then	CNTEN Hold Time	0.5		ns	
İ SRPT	REPEAT Setup Time	1.8		ns	
thrpt	REPEAT Hold Time	0.5		ns	
toe	Output Enable to Data Valid	—	4.6	ns	
tolz ⁽⁴⁾	Output Enable to Output Low-Z	1		ns	
tонz ⁽⁴⁾	Output Enable to Output High-Z	1	4.2	ns	
tCD1	Clock to Data Valid (Flow-Through) ⁽¹⁾		15	ns	
tCD2	Clock to Data Valid (Pipelined) ⁽¹⁾	—	4.2	ns	
tDC	Data Output Hold After Clock High	1		ns	
tскнz ⁽⁴⁾	Clock High to Output High-Z	1	4.2	ns	
tcklz ⁽⁴⁾	Clock High to Output Low-Z	1		ns	
tins	Interrupt Flag Set Time		7	ns	
tinr	Interrupt Flag Reset Time		7	ns	
tcols	Collision Flag Set Time		4.2	ns	
tcolr	Collision Flag Reset Time		4.2	ns	
tzzsc	Sleep Mode Set Cycles	2		cycles	
tzzrc	Sleep Mode Recovery Cycles	3		cycles	
Port-to-Port [Delay				
tco	Clock-to-Clock Offset	6		ns	

NOTES:

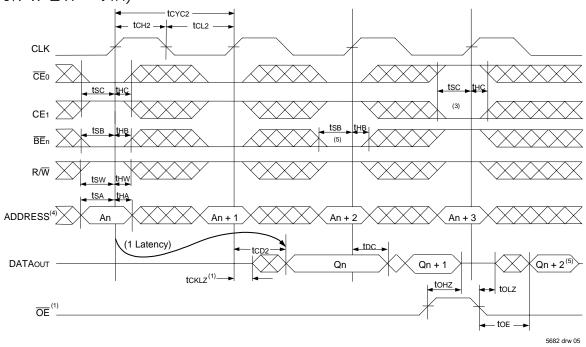
1. The Pipelined output parameters (tcvc2, tcb2) apply to either or both left and right ports when FT/PIPEx = Vbb (2.5V). Flow-through parameters (tcvc1, tcb1) apply when FT/PIPE = Vss (0V) for that port.

2. All input signals are synchronous with respect to the clock except for the asynchronous Output Enable (OE), FT/PIPE and OPT. FT/PIPE and OPT should be treated as DC signals, i.e. steady state during operation.

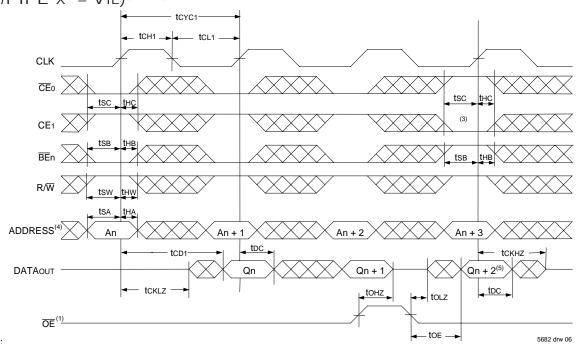
3. These values are valid for either level of VDDQ (3.3V/2.5V). See page 6 for details on selecting the desired operating voltage levels for each port.

4. Guaranteed by design (not production tested).



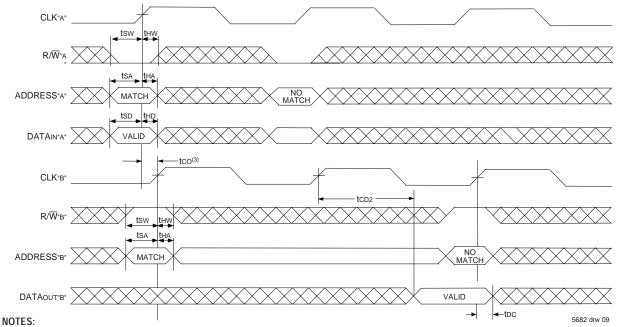






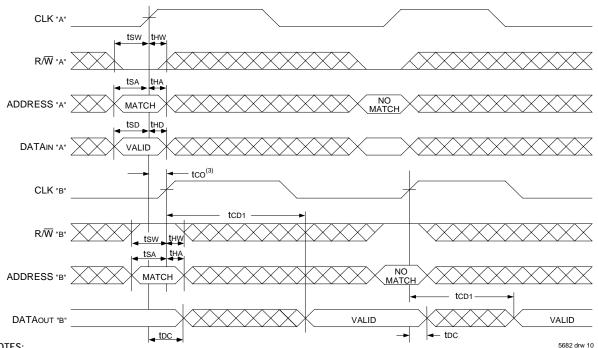
- 1. DE is asynchronously controlled; all other inputs depicted in the above waveforms are synchronous to the rising clock edge.
- 2. $\overline{ADS} = V_{IL}$, \overline{CNTEN} and $\overline{REPEAT} = V_{IH}$.
- 3. The output is disabled (High-Impedance state) by $\overline{CE}_0 = V_{IH}$, $CE_1 = V_{IL}$, $\overline{BE}_n = V_{IH}$ following the next rising edge of the clock. Refer to Truth Table 1.
- Addresses do not have to be accessed sequentially since ADS = VIL constantly loads the address on the rising edge of the CLK; numbers are for reference use only.
- 5. If BEn was HIGH, then the appropriate Byte of DATAOUT for Qn + 2 would be disabled (High-Impedance state).
- 6. "x" denotes Left or Right port. The diagram is with respect to that port.

Timing Waveform of Left Port Write to Pipelined Right Port Read^(1,2,4)



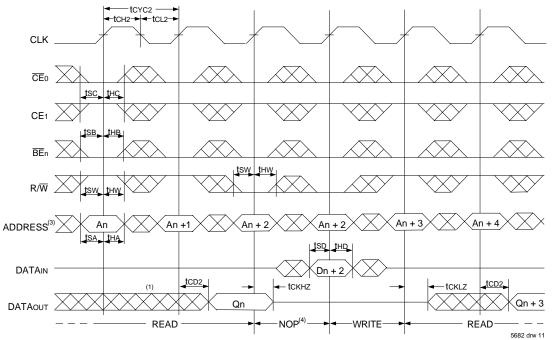
- 1. \overline{CE}_{0} , \overline{BE}_{n} , and $\overline{ADS} = V_{IL}$; CE_{1} , \overline{CNTEN} , and $\overline{REPEAT} = V_{IH}$.
- 2. $\overline{OE} = V_{IL}$ for Port "B", which is being read from. $\overline{OE} = V_{IH}$ for Port "A", which is being written to.
- 3. If tco ≤ minimum specified, then data from Port "B" read is not valid until following Port "B" clock cycle (ie, time from write to valid read on opposite port will be tco + 2 tcyc2 + tcp2). If tco > minimum, then data from Port "B" read is available on first Port "B" clock cycle (ie, time from write to valid read on opposite port will be tco + tcyc2 + tcp2).
- 4. All timing is the same for Left and Right ports. Port "A" may be either Left or Right port. Port "B" is the opposite of Port "A"

Timing Waveform with Port-to-Port Flow-Through Read^(1,2,4)



- 1. \overline{CE}_{0} , \overline{BE}_{n} , and $\overline{ADS} = V_{IL}$; CE_{1} , \overline{CNTEN} , and $\overline{REPEAT} = V_{IH}$.
- 2. $\overline{OE} = V_{IL}$ for the Right Port, which is being read from. $\overline{OE} = V_{IH}$ for the Left Port, which is being written to.
- If tco ≤ minimum specified, then data from Port "B" read is not valid until following Port "B" clock cycle (i.e., time from write to valid read on opposite port will be tco + tcyc + tcp1). If tco > minimum, then data from Port "B" read is available on first Port "B" clock cycle (i.e., time from write to valid read on opposite port will be tco + tcp1).
- 4. All timing is the same for both left and right ports. Port "A" may be either left or right port. Port "B" is the opposite of Port "A".

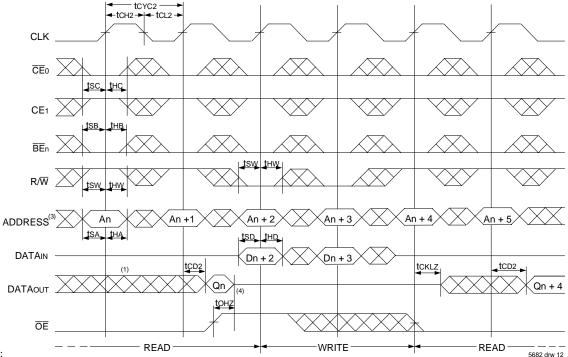
Timing Waveform of Pipelined Read-to-Write-to-Read ($\overline{OE} = VIL$)⁽²⁾



NOTES:

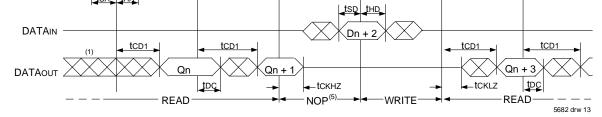
- Output state (High, Low, or High-impedance) is determined by the previous cycle control signals.
 CE0, BEn, and ADS = VIL; CE1, CNTEN, and REPEAT = VIH. "NOP" is "No Operation".
- Addresses do not have to be accessed sequentially since ADS = VIL constantly loads the address on the rising edge of the CLK; numbers 3. are for reference use only.
- 4. "NOP" is "No Operation." Data in memory at the selected address may be corrupted and should be re-written to guarantee data integrity.

Timing Waveform of Pipelined Read-to-Write-to-Read (**OE** Controlled)⁽²⁾

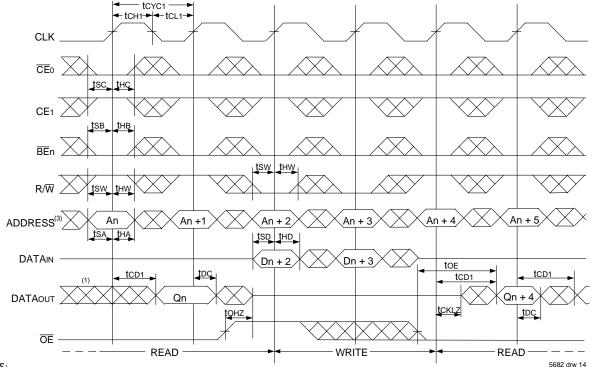


- 1. Output state (High, Low, or High-impedance) is determined by the previous cycle control signals.
- 2. \overline{CE}_{0} , \overline{BE}_{n} , and $\overline{ADS} = VIL$; CE1, \overline{CNTEN} , and $\overline{REPEAT} = VIH$.
- Addresses do not have to be accessed sequentially since ADS = VIL constantly loads the address on the rising edge of the CLK; numbers are for reference 3. use only.
- 4. This timing does not meet requirements for fastest speed grade. This waveform indicates how logically it could be done if timing so allows.

Timing Waveform of Flow-Through Read-to-Write-to-Read ($\overline{OE} = VIL$)⁽²⁾ ▲ tCYC1 → tCH1→ tCL1→ CLK \overline{CE}_0 tsc tHC CE1 2 BEn tHW tsw R/W tsw ADDRESS⁽³⁾ An An + 1An + 2 An + 2 An + 3 An + 4 tSA THA



Timing Waveform of Flow-Through Read-to-Write-to-Read (OE Controlled)⁽²⁾



NOTES:

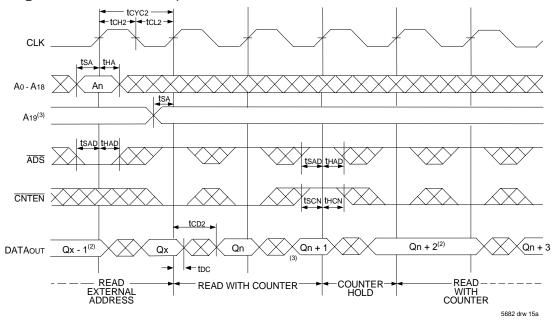
1. Output state (High, Low, or High-impedance) is determined by the previous cycle control signals.

2. \overline{CE}_0 , \overline{BE}_n , and $\overline{ADS} = VIL$; CE_1 , \overline{CNTEN} , and $\overline{REPEAT} = VIH$.

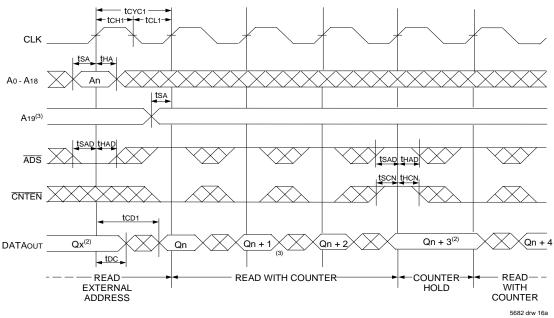
3. Addresses do not have to be accessed sequentially since ADS = VIL constantly loads the address on the rising edge of the CLK; numbers are for reference use only.

4. "NOP" is "No Operation." Data in memory at the selected address may be corrupted and should be re-written to guarantee data integrity.

Timing Waveform of Pipelined Read with Address Counter Advance⁽¹⁾

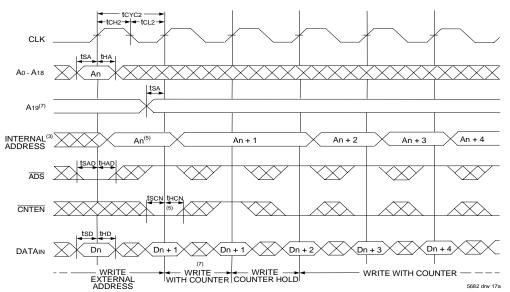


Timing Waveform of Flow-Through Read with Address Counter Advance⁽¹⁾

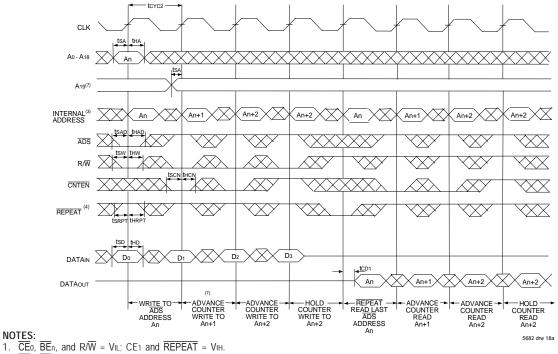


- 1. \overline{CE}_{0} , \overline{OE} , $\overline{BE}n = VIL$; CE1, R/W, and $\overline{REPEAT} = VIH$.
- 2. If there is no address change via $\overline{ADS} = VIL$ (loading a new address) or $\overline{CNTEN} = VIL$ (advancing the address), i.e. $\overline{ADS} = VIH$ and $\overline{CNTEN} = VIH$, then the data remains constant for subsequent clocks.
- 3. Address A19 must be managed as part of a full depth counter implementation using the IDT70T3509M. For physical addresses 00000H through 7FFFFH the value of a A19 is 0, while for physical addresses 80000H through FFFFH the value of A19 is 1. The user needs to keep track of the device counter and make sure that A19 is actively driven from 0-to-1 or 1-to-0 and held as needed at the appropriate address boundaries for full depth counter operation. As shown this transition reflects An = 7FFFFH or FFFFFH.

Timing Waveform of Write with Address Counter Advance (Flow-through or Pipelined Inputs)⁽¹⁾



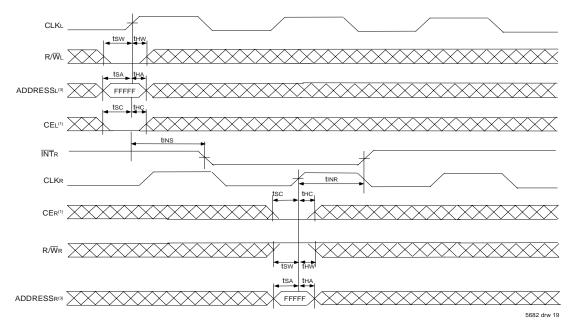
Timing Waveform of Counter Repeat^(2,6)



- 2. \overline{CE}_{0} , $\overline{BE}_{n} = VIL$; $CE_{1} = VIH$.
- 3. The "Internal Address" is equal to the "External Address" when ADS = VIL and equals the counter output when ADS = VIH.
- 4. No dead cycle exists during REPEAT operation. A READ or WRITE cycle may be coincidental with the counter REPEAT cycle: Address loaded by last valid ADS load will be accessed. For more information on REPEAT function refer to Truth Table II. A19 must be in the appropriate state when using the REPEAT function to guarantee the correct address location is loaded.
- 5. CNTEN = VIL advances Internal Address from 'An' to 'An +1'. The transition shown indicates the time required for the counter to advance. The 'An +1'Address is written to during this cycle.
- 6. For Pipelined Mode user should add 1 cycle latency for outputs as per timing waveform of read cycle for pipelined operations.
- 7. Address A19 must be managed as part of a full depth counter implementation using the IDT70T3509M. For physical addresses 00000H through 7FFFH the value of a A19 is 0, while for physical addresses 80000H through FFFFH the value of A19 is 1. The user needs to keep track of the device counter and make sure that A19 is actively driven from 0-to-1 or 1-to-0 and held as needed at the appropriate address boundaries for full depth counter operation. As shown this transition reflects An = 7FFFFH or FFFFFH.

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Waveform of Interrupt Timing⁽²⁾



NOTES:

- 1. $\overline{CE}_0 = V_{IL}$ and $CE_1 = V_{IH}$.
- 2. All timing is the same for Left and Right ports.

3. Address is for internal register, not the external bus, i.e. address needs to be qualified by one of the Address counter control signals.

Left Port					Right Port					
CLKL	R/₩ L ⁽²⁾	CEL ⁽²⁾	A19L-A0L	ĪNTL	CLKr	R/ W R ⁽²⁾	CER ⁽²⁾	A19R-A0R	INT R	Function
Ŷ	L	L	FFFFF	Х	Ŷ	Х	Х	Х	L	Set Right INTR Flag
↑	Х	Х	Х	Х	Ŷ	Н	L	FFFFF	Н	Reset Right INTR Flag
↑	Х	Х	Х	L	Ŷ	L	L	FFFFE	Х	Set Left INTL Flag
Ŷ	Н	L	FFFFE	Н	\uparrow	Х	Х	Х	Х	Reset Left INTL Flag

Truth Table III - Interrupt Flag⁽¹⁾

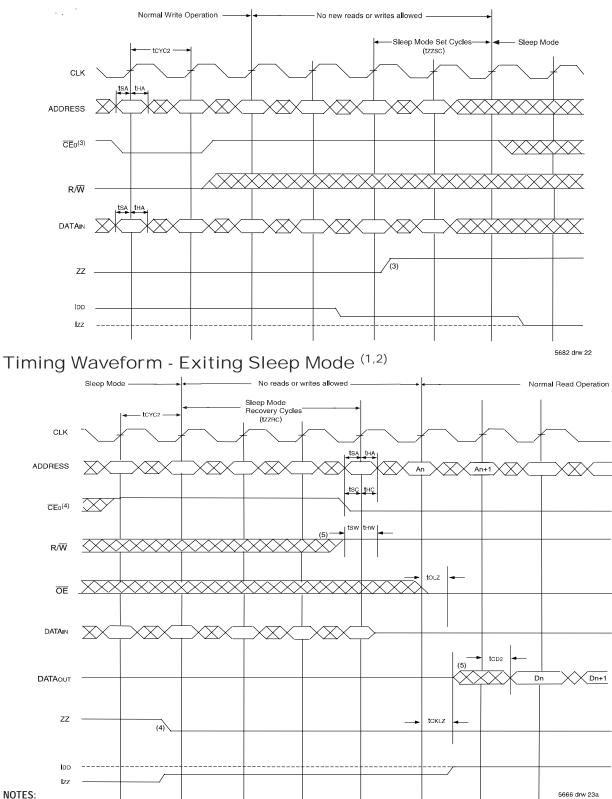
NOTES:

1. \overline{INT}_{L} and \overline{INT}_{R} must be initialized at power-up by Resetting the flags.

2. CE0 = VIL and CE1 = VIH, RW and CE are synchronous with respect to the clock and need valid set-up and hold times.

3. Address is for internal register, not the external bus, i.e. address needs to be qualified by one of the Address counter control signals.

Timing Waveform - Entering Sleep Mode (1,2)



- 1. CE1 = VIH.
- 2. All timing is same for Left and Right ports.
- 3. \overline{CE}_0 has to be deactivated ($\overline{CE}_0 = V_{IH}$) three cycles prior to asserting ZZ (ZZx = V_{IH}) and held for two cycles after asserting ZZ (ZZx = V_{IH}). 4. \overline{CE}_0 has to be deactivated ($\overline{CE}_0 = V_{IH}$) one cycle prior to de-asserting ZZ (ZZx = V_{IL}) and held for three cycles after de-asserting ZZ (ZZx = V_{IL}).
- 5. The device must be in Read Mode (R/W High) when exiting sleep mode. Outputs are active but data is not valid until the following cycle.

IDT70T3509M

High-Speed 2.5V 1024K x 36 Dual-Port Synchronous Static RAM

Functional Description

The IDT70T3509M provides a true synchronous Dual-Port Static RAM interface. Registered inputs provide minimal set-up and hold times on address, data, and all critical control inputs. All internal registers are clocked on the rising edge of the clock signal, however, the self-timed internal write pulse width is independent of the cycle time.

An asynchronous output enable is provided to ease asynchronous bus interfacing. Counterenable inputs are also provided to stall the operation of the address counters for fast interleaved memory applications.

The combination of a HIGH on \overline{CE} oand a LOW on CE1 for one clock cycle will power down the internal circuitry to reduce static power consumption. Multiple chip enables allow easier banking of multiple IDT70T3509Ms for depth expansion configurations. Two cycles are required with \overline{CE} LOW and CE1 HIGH to re-activate the outputs.

Width Expansion

The IDT70T3509M can be used in applications requiring expanded width. Through combining the control signals, the devices can be grouped as necessary to accommodate applications needing 72-bits or wider.

Sleep Mode

The IDT70T3509M is equipped with an optional sleep or low power mode on both ports. The sleep mode pin on both ports is asynchronous and active high. During normal operation, the ZZ pin is pulled low. When ZZ is pulled high, the port will enter sleep mode where it will meet lowest possible power conditions. The sleep mode timing diagram shows the modes of operation: Normal Operation, No Read/Write Allowed and Sleep Mode.

For normal operation all inputs must meet setup and hold times prior to sleep and after recovering from sleep. Clocks must also meet cycle high and low times during these periods. Three cycles prior to asserting ZZ (ZZx = VIH) and three cycles after de-asserting ZZ (ZZx = VIL), the device must be disabled via the chip enable pins. If a write or read operation occurs during these periods, the memory array may be corrupted. Validity of data out from the RAM cannot be guaranteed immediately after ZZ is asserted (prior to being in sleep). When exiting sleep mode, the device must be in Read mode (R/Wx = VIH) when chip enable is asserted, and the chip enable must be valid for one full cycle before a read will result in the output of valid data.

During sleep mode the RAM automatically deselects itself. The RAM disconnects its internal clock buffer. The external clock may continue to run without impacting the RAMs sleep current (Izz). All outputs will remain in high-Z state while in sleep mode. All inputs are allowed to toggle. The RAM will not be selected and will not perform any reads or writes.

IDT70T3509M High-Speed 2.5V 1024K x 36 Dual-Port Synchronous Static RAM

JTAG Functionality and Configuration

The IDT70T3509M is composed of four independent memory arrays, and thus cannot be treated as a single JTAG device in the scan chain. The four arrays (A, B, C and D) each have identical characteristics and commands but must be treated as separate entities in JTAG operations. Please refer to Figure 2.

JTAG signaling must be provided serially to each array and utilize the information provided in the Identification Register Definitions, Scan

Register Sizes, and System Interface Parameter tables. Specifically, all serial commands must be issued to the IDT70T3509M in the following sequence: Array D, Array C, Array B, Array A. Please reference Application Note AN-411, "JTAG Testing of Multichip Modules" for specific instructions on performing JTAG testing on the IDT70T3509M. AN-411 is available at www.idt.com.

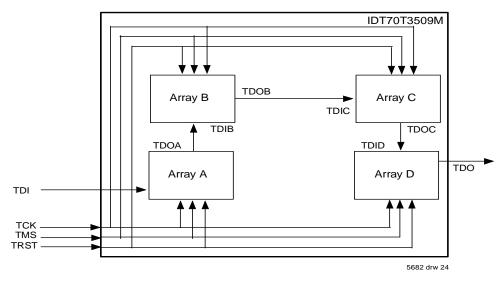
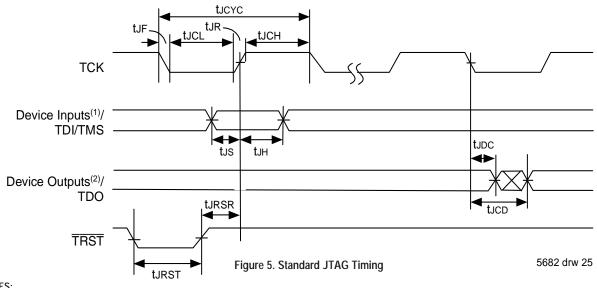


Figure 2. JTAG Configuration for IDT70T3509M

High-Speed 2.5V 1024K x 36 Dual-Port Synchronous Static RAM

JTAG Timing Specifications



NOTES:

1. Device inputs = All device inputs except TDI, TMS, and TRST.

2. Device outputs = All device outputs except TDO.

		70T3509M		
Symbol	Parameter	Min.	Max.	Units
ticyc	JTAG Clock Input Period	100		ns
tлсн	JTAG Clock HIGH	40		ns
tJCL	JTAG Clock Low	40		ns
UR	JTAG Clock Rise Time		3 ⁽¹⁾	ns
IJF	JTAG Clock Fall Time		3(1)	ns
U RST	JTAG Reset	50		ns
tursr	JTAG Reset Recovery	50		ns
ticd	JTAG Data Output		25	ns
tudc	JTAG Data Output Hold	0		ns
tıs	JTAG Setup	15		ns
tн	JTAG Hold	15		ns

JTAG AC Electrical Characteristics^(1,2,3,4)

NOTES:

1. Guaranteed by design.

2. 30pF loading on external output signals.

3. Refer to AC Electrical Test Conditions stated earlier in this document.

4. JTAG operations occur at one speed (10MHz). The base device may run at any speed specified in this datasheet.

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IDT70T3509M

High-Speed 2.5V 1024K x 36 Dual-Port Synchronous Static RAM

Commercial Temperature Range

Identification Register Definitions

Instruction Field Array D	Value Array D	Instruction Field Array C	Value Array C	Instruction Field Array B	Value Array B	Instruction Field Array A	Value Array A	Description
Revision Number (31:28)	0x0	Revision Number (63:60)	0x0	Revision Number (95:92)	0x0	Revision Number (127:124)	0x0	Reserved for Version number
IDT Device ID (27:12)	0x333	IDT Device ID (59:44)	0x333	IDT Device ID (91:76)	0x333	IDT Device ID (123:108)	0x333	Defines IDT Part number
IDT JEDEC ID (11:1)	0x33	IDT JEDEC ID (43:33)	0x33	IDT JEDEC ID (75:65)	0x33	IDT JEDEC ID (107:97)	0x33	Allows unique identification of device vendor as IDT
ID Register Indicator Bit (Bit 0)	1	ID Register Indicator Bit (Bit 32)	1	ID Register Indicator Bit (Bit 64)	1	ID Register Indicator Bit (Bit 96)	1	Indicates the presence of an ID Register

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Scan Register Sizes

Register Name	Bit Size Array A	Bit Size Array B	Bit Size Array C	Bit Size Array D	Bit Size 70T3509M
Instruction (IR)	4	4	4	4	16
Bypass (BYR)	1	1	1	1	4
Identification (IDR)	32	32	32	32	128
Boundary Scan (BSR)	Note (3)				

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System Interface Parameters

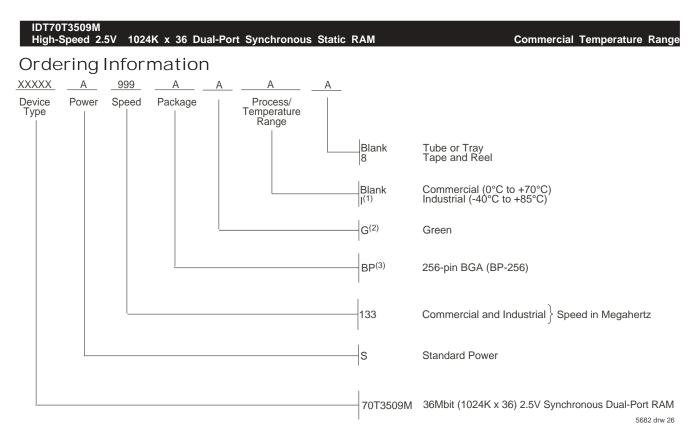
Instruction	Code	Description
EXTEST	000000000000000000000000000000000000000	Forces contents of the boundary scan cells onto the device outputs ⁽¹⁾ . Places the boundary scan register (BSR) between TDI and TDO.
BYPASS	11111111111111	Places the bypass register (BYR) between TDI and TDO.
IDCODE	0010001000100010	Loads the ID register (IDR) with the vendor ID code and places the register between TDI and TDO.
HIGHZ	0100010001000100	Places the bypass register (BYR) between TDI and TDO. Forces all device output drivers except INTx to a High-Z state.
CLAMP	0011001100110011	Uses BYR. Forces contents of the boundary scan cells onto the device outputs. Places the bypass register (BYR) between TDI and TDO.
SAMPLE/PRELOAD	0001000100010001	Places the boundary scan register (BSR) between TDI and TDO. SAMPLE allows data from device inputs ⁽²⁾ to be captured in the boundary scan cells and shifted serially through TDO. PRELOAD allows data to be input serially into the boundary scan cells via the TDI.
RESERVED	0101010101010101, 0111011101110111, 1000100010001000, 100110011001, 1010101010101010, 1011101110111011, 1100110011001100	Several combinations are reserved. Do not use codes other than those identified above.
PRIVATE	0110011001100110,1110111011101110, 11011101	For internal use only.

NOTES:

1. Device outputs = All device outputs except TDO.

3. The Boundary Scan Descriptive Language (BSDL) file for this device is available on the IDT website (www.idt.com), or by contacting your local IDT sales representative.

^{2.} Device inputs = All device inputs except TDI, TMS, and $\overline{\text{TRST}}$.



NOTES:

1. Contact your local sales office for Industrial temp range in other speeds, packages and powers.

- 2. Green parts available. For specific speeds, packages and powers contact your local sales office.
- LEAD FINISH (SnPb) parts are in EOL process. Product Discontinuation Notice PDN# SP-17-02

3. BP-256 package thickness is 1.76mm nominal. This is thicker than the BC-256 package (1.40mm nominal) used for the lower density IDT dual-port products.

Datasheet Document History:

11/09/04: 03/24/05:	Initial Public Release of Preliminary Datasheet Page 1 Added I-temp offering to features
	Page 6 Added I-temp information to the Recommended Operating Temperature and Supply Voltage table
	Page 8 Added I-temp values to the DC Electrical Characteristics table
	Page 10 Added I-temp to the heading of the AC Electrical Characteristics table
	Page 23 Added I-temp to ordering information
	Page 1 Added green availability to features
	Page 1 - 23 Removed Preliminary status
06/14/05:	Page1 Added feature to highlight footprint compatibility
	Page 3 & 23 Added a footnote to highlight package thickness of BP-256 vs. BC-256
08/27/07:	Page 1 Functional Block Diagram changed to correct chip enable logic and added footnote 2 referencing Truth Table I
07/28/08:	Page 8 Corrected a typo in the DC Chars table
01/19/09:	Page 23 Removed "IDT" from orderable part number
07/15/14:	Page 23 Added Tape & Reel to Ordering Information
02/14/18:	Page 23 Ordering Information restored from 70T3719_99 to 70T3509M
	Product Discontinuation Notice - PDN# SP-17-02
	Last time buy expires June 15, 2018
	Last time buy expires June 15, 2018



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